SiRRSO1[®] Ruggedised Angular Rate Sensor





The SiRRS01[®] angular rate sensor has evolved from the highly successful Vibrating Structure Gyroscope developed for aerospace applications which has been in service since 1990.

This MEMS implementation of our VSG technology, offers continued advancement in miniaturisation and reliability. Designed to provide high performance operation under harsh environmental conditions, the SiRRS01[®] is ideally suited for a wide range of applications.

The SiRRS01[®] is underpinned by Silicon Sensing's commitment to the technical backup and long term support necessary for major procurement programmes.

Key features

- Micro machined silicon (MEMS) technology
- Affordable, robust and rugged design
- Hermetically sealed
- Excellent shock and vibration performance
- Long life and exceptional reliability
- Comprehensive Built In Test (BIT)
- Integrated temperature sensor
- Compact and lightweight
- Low power consumption
- Sensor modelling data available



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SiRRS01[®] Ruggedised Angular Rate Sensor

For full technical datasheets please go to our website where the documents can be downloaded

All dimensions in millimetres





vnical Data

l ypical Data	SiRRS-01
Angular Rate Range	±110°/s (other ranges available - see table)
Scale Factor	
Nominal	18.18mV/°/s
Variation over temperature range	< ±3%
Non-linearity	±1% of full scale
Repeatability	±0.05% 1σ
Bias	
Setting (at +20°C)	< ±0.3°/s
Variation over temperature range	< ±3°/s
Instability	5°/hr
Repeatability	±0.03°/s 1σ
Angular Random Walk	< 0.38°/ √ hr
g sensitivity	< 7°/hr/g
Bandwidth	> 50Hz (90° phase)
Noise (in-band)	< 0.35°/s rms
Environment	
Operating temperature	-40°C to +75°C
Relative humidity	95%
Shock (operational)	60g (30ms, ½ sine)
Vibration (operational)	10g rms (20Hz to 2kHz)
Cross-axis sensitivity	< +2%
Mass	< 35 gram
Electrical	
Supply voltage	+5V, 0V, -5V
Supply current	< 50mA (each, steady state)
General	
Built In Test (BIT)	Command BIT, Alarm BIT
Start-up time	300ms
Temperature output	16.9mV/°C (0V at 25°C)
MTBF	300,000hr
BoHS Compliant	No

5°/hr	Command BIT 3 7 Rate Output
±0.03°/s 1σ	Alarm BIT 2 6 0V
< 0.38°/ √ hr	+5V 1 5 Temperature
< 7°/hr/g	
> 50Hz (90° phase)	Silicon Sensing Systems Limited Clittaford Road, Southway, Plymouth, Devon PL6 6DE United Kingdom
< 0.35°/s rms	
-40°C to +75°C	T +44 (0)1752 723330 F +44 (0)1752 723331 E sales@siliconsensing.com W siliconsensing.com
95%	
60g (30ms, ½ sine)	

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Pin Number

RRS01-01

RRS01-03

RRS01-05

RRS01-07

RRS01-09

Pin Connections

Specification subject to change without notice.

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SILICON^C SENSING

Rate Range

±110%s

±300°/s

±50°/s

±1.500%s

9 Case Ground

±200°/s

-5V **4 8** Rate Reference

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